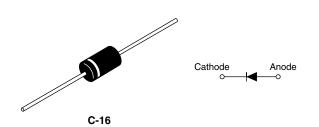


Vishay High Power Products

Schottky Rectifier, 3.3 A



PRODUCT SUMMARY				
I _{F(AV)}	3.3 A			
V _R	30/40 V			

FEATURES

- Low profile, axial leaded outline
- High frequency operation



- Very low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free plating
- Designed and qualified for industrial level

DESCRIPTION

The 31DQ.. axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rectangular waveform	3.3	A	
V _{RRM}		30/40	V	
I _{FSM}	t _p = 5 μs sine	450	A	
V _F	3 Apk, T _J = 25 °C	0.57	V	
TJ		- 40 to 150	°C	

VOLTAGE RATINGS						
PARAMETER	SYMBOL	31DQ03	31DQ04	UNITS		
Maximum DC reverse voltage	V_{R}	30	40	V		
Maximum working peak reverse voltage	V_{RWM}	30	40	V		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 4	I _{F(AV)}	50 % duty cycle at T _L = 117 °C, rectangular waveform		3.3	
Maximum peak one cycle non-repetitive surge current See fig. 6	I	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	450	Α
	IFSM	10 ms sine or 6 ms rect. pulse		90	
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, \ I_{AS} = 1.0 \text{A}, \ L = 12 \text{mH}$		6.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		Α	

31DQ03, 31DQ04

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	3 A	T _J = 25 °C	0.57	V
		6 A		0.71	
		3 A	T _J = 125 °C	0.51	
		6 A		0.62	
Maximum reverse leakage current	_{DM} (!)	T _J = 25 °C	$V_B = Rated V_B$	1	- mA
See fig. 4		T _J = 125 °C	V _R = nateu V _R	20	
Typical junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		190	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		9.0	nΗ
Maximum voltage rate of charge	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C	
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation Without cooling fin	80	°C/W	
Typical thermal resistance, junction to lead	R _{thJL}	With fin 20 mm x 20 mm (0.79" x 0.79") 1.0 mm (0.04") thickness	15	*C/VV	
Approximate weight			1.2	g	
Approximate weight			0.042	OZ.	
Marking device		Case style C-16	31D	31DQ03	
			31D	31DQ04	

Note

$$^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$$



Schottky Rectifier, 3.3 A Vishay High Power Products

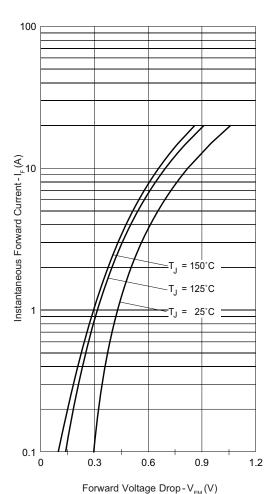


Fig. 1 - Maximum Forward Voltage Drop Characteristics

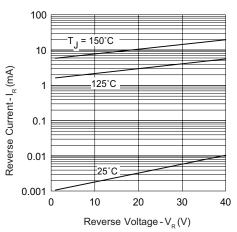


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

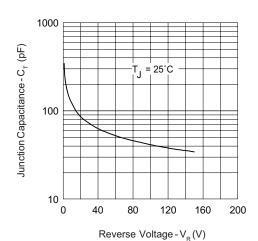
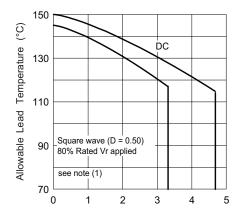


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



Average Forward Current - IF_(AV)(A)

Fig. 4 - Maximum Allowable Lead Temperature vs.

Average Forward Current

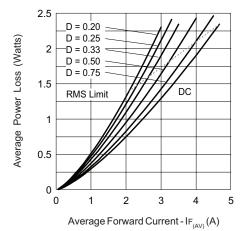


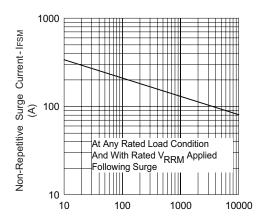
Fig. 5 - Forward Power Loss Characteristics

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R$ (1 - D); I_R at $V_{R1} = 80$ % rated V_R

Vishay High Power Products Schottky Rectifier, 3.3 A



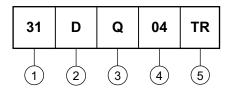


Square Wave Pulse Duration - t_p (microsec)

Fig. 6 - Maximum Non-Repetitive Surge Current

ORDERING INFORMATION TABLE

Device code



1 - 31 = 3.1 A (axial and small packages - current is x 10)

2 - D = DO-201 package

3 - Q = Schottky Q.. series

03 = 30 V 04 = Voltage ratings 03 = 40 V

• TR = Tape and reel package (1200 pcs)

• None = Box package (500 pcs)

LINKS TO RELATED DOCUMENTS			
Dimensions http://www.vishay.com/doc?95242			
Part marking information http://www.vishay.com/doc?95304			
Packaging information http://www.vishay.com/doc?95309			



Vishay

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